DATA SHEET

Revision: 1.0

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AG1KLP

Low power and low cost FPGA

General Description

AG1KLP family provides low cost, ultra-low power, SRAM-based FPGAs, with density is ranging from 640 up to 1280 Look-Up Tables(LUTs). The devices feature Embedded Block Memory (EBR), Distributed RAM, and Phase Locked Loops (PLLs), while offering small footprint package WLSCP, ucBGA and QFN. The devices are designed for ultra low power and cost while providing programmable solutions for a wide range of applications, especially in consumer and mobile device products.

Features

- Low power and low cost FPGA.
- Flexible logic architecture based on LUT.
- Ultra-low power, as low as 50 μ A standby typical Icc (1.2V Vcc).
- Broad range of package options, small footprint package for consumer and mobile application.
- Provides PLL per device provide clock multiplication and phase shifting
- 3.3-V, 2.5-V, 1.8-V, 1.5-V LVCMOS and LVTTL standards
- Flexible device configuration through SPI interface.
- Table 1-1 Shows AG1KLP family features

Feature	AG1KLP
LUTs	640, 1280
Distributed RAM (Kbits)	10
EBR SRAM (Kbits)	68
Maximum User I/O pins	40
Number of PLLs	1
Package	16-Pin WLCSP
	36-Pin ucBGA
	49-Pin ucBGA
	48-Pin QFN

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1. AG1KLP Architecture Overview

1.1. Functional Description

The AG1KLP devices contain an industrial state-of-the art two-dimensional row- and column-based architecture to implement custom logic. Column and row interconnects of varies speeds provide signal interconnects between logic array blocks (LABs) and IOs.

The logic array consists of LABs, with 16 logic slices (LS) in each LAB. A slice is a small unit of logic providing efficient implementation of user logic functions. LABs are grouped into rows and columns across the device. The AG1KLP devices' density is ranging from 640 to 1280 slices.

The device global clock network consists of up to 8 global clock lines that drive through the entire device. The global clock network can provide clocks for all resources within the device, such as input/output elements (IOEs), slices. The global clock lines can also be used for other high fan-out signals.

Each device I/O pin is fed by an IOE located at the ends of LAB rows and columns around the periphery of the device. I/O pins support various single-ended standards. Each IOE contains a bidirectional I/O buffer.

1.2. Logic Array Blocks

Each Logic Array Block consists of 16 slices, SLICE carry chains, SLICE control signals, a local interconnect, a look-up table (LUT) chain, and register chain connection lines. There are 32 possible unique inputs into an SLICE, with an additional 16 local feedback input lines fed by SLICE outputs in the same SLICE. The local interconnect transfers signals between SLICEs in the same block. LUT chain connections transfer the output of one SLICE's LUT to the adjacent SLICE for fast sequential LUT connections within the same SLICE. Register chain connections transfer the output of one SLICE's register to the adjacent SLICE's register within a block. The AG1KLP software places associated logic within an SLICE or adjacent SLICES, allowing the use of local, LUT chain, and register chain connections for performance and area efficiency.

1.3. Logic Element

The smallest unit of logic in AG1KLP architecture, the slice, is compact and provides advanced and flexible features with efficient logic utilization. Each slice features:

- Industrial standard four-input look-up table (LUT4), which is a function generator that can implement any combinatorial logic function of four inputs.
- A programmable register

Carry Out Synchronous Shift Register Reset Input LUT4 & Synchronous & Q D Data Carry Chain Shift Control Inputs Clk Enabl Reset Lut Output Clk ClkEnable Asynchronous Reset Shift Register Carry In Output

Figure 1-1 AG1KLP Logic SLICE

Each slice's register has data, clock, clock enable, and clear inputs.

1.4. FlexTrack Interconnect

In AG1KLP device architecture, FlexTrack interconnect consists of continuous, performance-optimized routing lines used for inter- and intra- design block connectivity. The FlexTrack connects to LEs, and IO pins with row and column connection that span fixed distances.

1.5. Global Signals

Each device has eight dual-purpose dedicated clock pins. The eight global clock lines drive throughout the entire device. The global clock network can provide clocks for all resources within the device including LEs, local interconnect. The global lines can be used for global signals distribution.

1.6. Phase Locked Loops (PLLs)

The AG1KLP provides PLL support. The PLL has four output The source of the PLL input divider can come from an external pin or from internal routing. There are four sources of feedback signals to the feedback divider: from CLKINTFB (internal feedback port), from the global clock nets, from the output of the post scalar divider, and from the routing (or from an external pin). There is a PLL_LOCK signal to

indicate that the PLL has locked on to the input clock signal. Figure 1-2 shows the PLL diagram.

The PLLs provide the ability to synthesize clock frequencies. Each PLL has four dividers associated with it: input clock divider, feedback divider, post scalar divider, and secondary clock divider.

Phase adjustment

N Divider (1-64)

Phase defeators (1

Figure 1-2. PLL Diagram

PLL Output Features:

- Output frequency is 16MHz-275MHz.
- VCO range 533MHz 1066MHz
- Jitter is about 5%.
- Static current <1uA
- Operating Temperature Range:- 25[°]C ~ 125[°]C
- Operation Voltage: 1.2V \pm 5%

PLL Input Features:

- 10MHz-133MHz.
- Power down PLL.
- A reset input.

1.7. Embedded Block RAM

AG1KLP contains 14 Embedded Block RAMs (EBRs). The EBR consists of a 4.5Kbit RAM, with dedicated input and output registers. This memory can be used for a wide variety of purposes including data buffering and FIFO. The EBR block can implement single port, dual port, simple dual port, or FIFO memories. Each block can be used in a variety of depths and widths as shown in Table 1-1.

Memory Mode	Configurations
Single Port	4096 x 1
	2048 x 2
	1024 x 4
	512 x 9
	256 x 18
	128 x 36
True Dual Port	4096 x 1
	2048 x 2
	1024 x 4
	512 x 9
	256 x 18
Pseudo Dual Port	4096 x 1
	2048 x 2
	1024 x 4
	512 x 9
	256 x 18
	128 x 36
FIFO	4096 x 1
	2048 x 2
	1024 x 4
	512 x 9
	256 x 18
\wedge	128 x 36

If desired, the contents of the RAM can be pre-loaded during device configuration.

By preloading the RAM block during the chip configuration cycle and disabling the write controls, the EBR block can also be utilized as a ROM.

Larger and deeper blocks of RAM can be created using EBR Blocks.

In all the RAM modes, the input data and addresses for the ports are registered at the input of the memory array. The output data of the memory is optionally registered at the memory array output.

1.8.I/O Pin

I/O supported features:

- Supports 3.3-V, 2.5-V, 1.8-V, and 1.5-V logic levels
- Programmable drive strength, bus-hold, pull-up resistors, open-drain output, and Schmitt triggers input.
- 3.3-V, 2.5-V, 1.8-V, 1.5-V LVCMOS and LVTTL standards

2. Device Configuration

AG1KLP device supports SPI master or slave mode configuration. External Flash provides a non-volatile storage for the configuration data. Additionally, the configuration data can be downloaded from an external processor, microcontroller, or DSP processor using the SPI interface.

2.1. Configuration Mode Selection

The AG1KLP configuration mode is selected according to the following priority described below.

- After exiting the Power-On Reset (POR) state or when CRESET_B returns High after being held Low, the AG1KLP device samples the logical value on its SPI_SS_B pin. Like other programmable I/O pins, the SPI_SS_B pin has an internal pull-up resistor.
- If the SPI_SS_B pin is sampled as a logic '1' (High), then the device configures using the SPI Master Configuration Interface.
- If the SPI_SS_B pin is sampled as a logic '0' (Low), then the device waits to be configured from an external controller or from another device in SPI Master Configuration Mode using an SPI-like interface.

2.2. CONFIG Pins

The AG1KLP has a set of CONFIG pins that are used to program and configure the device. The CONFIG pins are dual-function, meaning they can be recovered as user I/O after configuration is complete. Table 2-1 shows the CONFIG pins.

Table 2-1, CONFIG Pins

Pin Name	Pin Direction	Description	
CRESET_B	Input	Configuration Reset input, active-low. No internal pull-up resistor.	
CDONE	Output	Configuration Done output. The pin has a permanent, weak internal pull-up resistor to the VCCIO_2 rail. Depending on the frequency of configuration and the capacitance on CDONE node, then CDONE pin must be tied to an external pullup resistor connected to the VCCIO_2 supply. The SWG16 package	
		CDONE pin can be used as a user output.	
SPI_SS_B	Input/Output	An important dual-function, active-low slave select pin. After the device exits POR or CRESET_B is toggled (High-Low- High), it samples the SPI_SS_B to select the configuration mode (an output in Master mode and an input in Slave mode).	
SPI_SI	Input	A dual-function, serial input pin in both configuration modes.	
SPI_SO	Output	A dual-function, serial output pin in both configuration modes.	

SPI_SCK	Input/Output	A dual-function clock signal. An output in Master mode and input
		in Slave mode.

3. Power-On Reset Circuitry

3.1. Power-On Reset Circuitry

When power is applied to AG1KLP devices, the POR circuit monitors _{VCC} and begins SRAM download at an approximate voltage of 1.2V AG1KLP devices.

Entry into user mode is gated by whether _{VCCIO} bank2 are powered with sufficient operating voltage. If _{VCC} and _{VCCIO} are powered simultaneously, the device enters user mode.

For AG1KLP when in user mode, the POR circuitry continues to monitor the V_{CC} (but not V_{CCIO}) voltage level to detect a brown-out condition. If there is a V_{CC} voltage sag at during user mode, the POR circuit resets the SRAM and tri-states the I/O pins. Once V_{CC} rises back to approximately 1.2V, the SRAM download restarts and the device begins to operate.

3.2. Power Saving Options

AG1KLP devices have been designed with features that allow users to meet the static and dynamic power requirements of their applications by controlling various device subsystems power-on-reset circuitry, PLLs, etc.

4. DC Electrical Characteristics

Table 4-1 Recommended Operating Conditions

Symbol	Parameter		Min.	Max.	Units
Vcc	Core Supply Voltage		1.14	1.26	V
VCCPLL	PLL Supply Voltage		1.14	1.26	V
Vccio	I/O Driver Supply	VCCIO0,2	1.71	3.46	V
	Voltage	VCC_SPI	1.71	3.46	V

Table 4-2 Recommended Operating Conditions

Symbol	Parameter	Тур.	Units
IIL, IIH	Input or I/O Leakage	+/-1	μ A
C1	I/O Capacitance	6	pF
C2	Global Input Buffer Capacitance	6	pF
VHYST	Input Hysteresis	200	mV
IPU	Internal PIO Pull-up Current	-35 (VCCIO = 1.8V)	μ A
		-49 (VCCIO = 2.5V)	μ A
		-65 (VCCIO = 3.3V)	μ A

Icc	Core Power Supply	50	μА
ICCPLL	PLL Power Supply	1	μ A

Table 4-3 Peak Startup Supply Current

Symbol	Parameter	Max.	Units
ICCPEAK	Core Power Supply	6.5	mA
ICCPLLPEAK	PLL Power Supply	1.5	mA
ICCIOPEAK,	Bank Power Supply	3.4	mA
ICC_SPIPEAK			

Table 4-4 IO Single-Ended DC Electrical Characteristics

Input/	VIL		VIH		VOL	VOH	IOL	IOH Max.
Output	Min. (V)	Max.	Min. (V)	Max. (V)	Max.	Min. (V)	Max.	(mA)
Standard		(V)			(V)		(mA)	
LVCMOS	-0.3	0.8	2.0	VCCIO	0.4	Vccio	8,16,24	-8,-16,-24
3.3				+0.2V		-0.5		
LVCMOS	-0.3	0.7	1.7	Vccio	0.4	Vccio	6,12,18	-6,-12,-18
2.5				+0.2V		-0.5		
LVCMOS	-0.3	0.35	0.65	VCCIO	0.4	Vccio	4, 8,12	-4, -8,-12
1.8		Vccio	Vccio	+0.2V		-0.4		

Table 4-5 Power-On-Reset Voltage Levels

Symbol	Parameter		Min.	Max	Units
VPORUP	Power-On-Reset	vcc	0.55	0.8	V
	ramp-up trip point	1			
	(band gap based	VCCIO_2	0.9	1.1	V
	circuit monitoring				
	VCC, VCCIO_2,	VCC_SPI	0.9	1.1	V
	VCC_SPI)				

5. Timing Characteristics

Table 5-1 Typical Building Block Function Performance

Register-to-Register Performance				
Function Timing Units				
16-bit counter	250	MHz		
64-bit counter	100	MHz		

6. Pin-Outs

Refer to Pin-Outs printouts for AG1KLP device family.

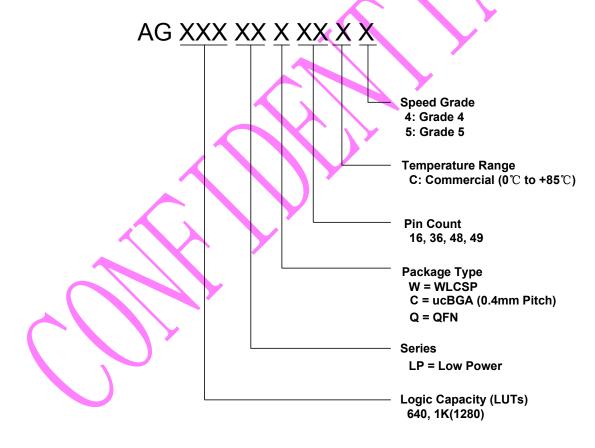
Pin name	Ball List(BGA36) Pin name		Ball List(BGA36)	
IOL_2B	A1	IOL_7A_GBIN6	D1	
IOT_89	A2	GNDPLL	D2	
IOT_84_GBIN1	A3	GND	D2 🔨	
VDDIO_0_1	A4	GND	D3	
VPP_FAST	A5	GND	D3	
VPP_2V5	A6	GND	D4	
IOL_2A	B1	IOB_47_SS	D5	
VCC	B2	IOR_55	Ď6	
VCCPLL	B2	IOL_7B	E1	
VCC	B2	IOB_34	E2	
IOT_85_GBIN0	В3	IOB_42_CBSEL0	E3	
IOR_61_GBIN2	B4	IOB_44_SDO	E4	
Pin name	Ball List(BGA36)	Pin name	Ball List(BGA36)	
IOR_63	B5	IOB_46_SCK	E5	
IOR_64	B6	IOR_54	E6	
IOL_6B_GBIN7	C1	VDDIO_2_3	F1	
IOL_6A	C2	IOB_35_GBIN5	F2	
IOT_90	C3	IOB_43_CBSEL1	F3	
CDONE	C4	CRESET_B	F4	
IOR_60_GBIN3	C5	IOB_45_SDI	DI F5	

7. Reference and Ordering Information

7.1.Software

AG1KLP Software tools support from RTL to bit stream configuration implementation and programming. Supported operating system platforms include Microsoft Windows and Linux.

7.2. Ordering Information



8. Recommended Reflow Profile

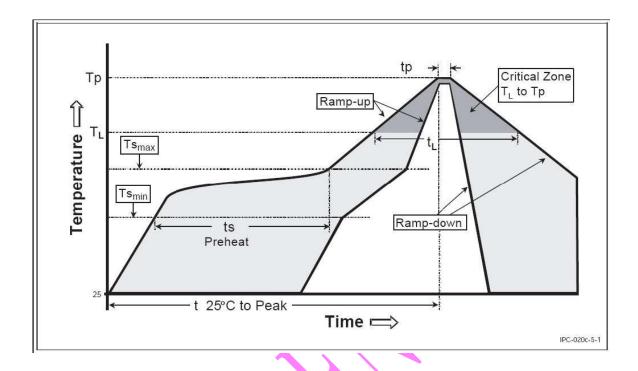


Figure. 8-1 Classification Reflow Profile

Table 8-1 Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average Ramp-Up Rate	3 °C/second max.	3 °C/second max.
(TSmax to Tp)	7	
Preheat		
-Temperature Min (Tsmin)	100 ℃	150 ℃
-Temperature Max (Tsmax)	100 ℃	200 ℃
-Time (tsmin to tsmax)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (TL)	183 ℃	217℃
-Time (tL)	60-150seconds	60-150 seconds
Peak /Classification	See Table 10	See Table 11
Temperature(Tp)		
Time within 5 oC of actual Peak	10-30 seconds	20-40 seconds
Temperature (tp)		
Ramp-Down Rate	6 °C/second max.	6 °C/seconds max.
Time 25 oC to Peak	6 minutes max.	8 minutes max.
Temperature		

Table 8-2 Sn-Pb Eutectic Process – Package Peak Reflow Temperatures

Package Thickness	Volume mm3	Volume mm3	
	<350	≥350	
<2.5mm	240 + 0/-5 °C	225 + 0/-5 °C	
≥2.5mm	225 + 0/-5 °C	225 + 0/-5 °C	

Table 8-3 Pb-free Process – Package Classification Reflow Temperatures

Package Thickness	Volume mm3 <350	Volume mm3 350-2000	Volume mm3 >2000
<1.6mm	260 + 0 °C *	260 + 0 °C *	260 + 0 ℃ *
1.6mm – 2.5mm	260 + 0 °C *	250 + 0 °C *	245 + 0 ℃ *
≥2.5mm	250 + 0 °C *	245 + 0 °C *	245 + 0 °C *

^{*}Tolerance : The device manufacturer/supplier shall assure process compatibility up to and including the stated classification temperature(this mean Peak reflow temperature +0 °C. For example 260+0 °C) at the rated MSL Level.

- Note 1: All temperature refer topside of the package. Measured on the package body surface.
- Note 2: The profiling tolerance is +0 °C, -X °C (based on machine variation capability)whatever is required to control the profile process but at no time will it exceed -5 °C. The producer assures process compatibility at the peak reflow profile temperatures defined in Table 9-3.
- Note 3: Package volume excludes external terminals(balls, bumps, lands, leads) and/or non integral heat sinks.
- Note 4: The maximum component temperature reached during reflow depends on package the thickness and volume. The use of convection reflow processes reduces the thermal gradients between packages. However, thermal gradients due to differences in thermal mass of SMD package may sill exist.
- Note 5: Components intended for use in a "lead-free" assembly process shall be evaluated using the "lead free" classification temperatures and profiles defined in Table8-1, 8-2, 8-3 whether or not lead free.

9. Change List

The following table summarizes revisions to this document.

REV	DATE	AUTHER	CHANGE DESCRIPTION
V1.0	03/27/2015		Release Version 1.0

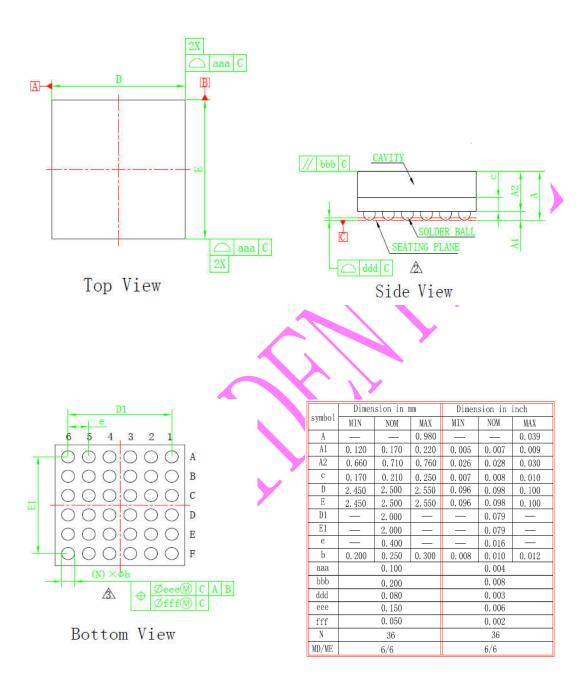
10. RoHS Compliant

The product does not contain lead, mercury, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) or polybrominated diphenyl ethers (PBDE), and are therefore considered RoHS compliant.

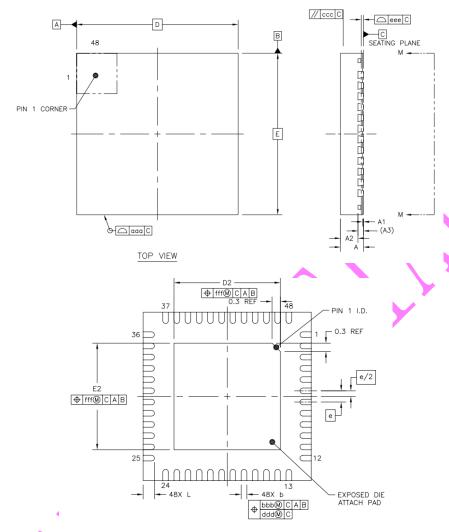
11. ESD Precautions

ESD protection circuitry is contended in this device, but special handling precautions are required.

Package Diagram(BGA36)



Package Diagram(QFN48)



BOTTOM VIEW
VIEW M-M

			MULINETED		
DESCRIPTION		SYMBOL	MIN	MILLIMETER NOM	MAX
TOTAL THICKNESS		Α	0.8	0.85	0.9
STAND OFF		A1	0	0.035	0.05
MOLD THICKNESS		A2		0.65	0.67
L/F THICKNESS		A3	0.203 REF		
LEAD WIDTH		b	0.15	0.20	0.25
DODY CIZE	X	D	5.90	6.00	6.10
BODY SIZE	Υ	E	5.90	6.00	6.10
LEAD PITCH		е		0.40 BSC	
EP SIZE	Х	D2	3.70	3.80	3.90
LF SIZE	Υ	E2	3.70	3.80	3.90
LEAD LENGTH		L	0.30	0.40	0.50
PACKAGE EDGE TOLE	RANCE	aaa	0.1		
LEAD OFFSET		bbb	0.07		
MOLD FLATNESS		ccc	0.1		
		ddd	0.05		
COPLANARITY		eee	0.08		
EXPOSED PAD OFFSET		fff		0.1	